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INFORMATION DISCLOSURE					APPLICANT				
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	AN	Organic Filed-Effect Transistors" Proc. MRS Fall Meeting (2003) K10.52							
/B.W./	AO	Gundlach, D.J. et al. "Thin-Film Transistors Based on Well-Ordered Thermally Evaporated Naphthacene Films" <i>Applied Physics Letters</i> (2002) Vol. 80, No. 16, pp 2925-2927							
/B.W./	AP	Malenfant, P. et al. "N-type Organic Thin-film Transistor with High Field-effect Mobility Based on a N,n'-dialkyl-3,4,9,10-perylene Tetracarboxylic Diimide Derivative" <i>Applied Physics Letters</i> (2002) Vol. 80, No. 14, pp 2517-2519							
/B.W./	AQ	Katz, H.E. et al. "A Soluble and Air-Stable Organic Semiconductor with High Electron Mobility"  Nature (2000) Vol. 404, pp 478-480							
/B.W./	AR	Bao, Z. et al. "New Air-Stable n-Channel Organic Thin Film Transistors"  J. Am. Chem. Soc. (1998) Vol. 120, No. 1, pp 207-208							
/B.W./	AS	Lin, Y.Y. et al. "Stacked Pentacene Layer Organic Thin-Film Transistors with Improved Characteristics" <i>IEEE Electron Device Letters</i> (1997) Vol. 18, No. 12, pp 606-608							
EXAMINER	/Bryan Wils	ryan Wilson/ DATE CONSIDERED 09/03/2007							
EXAMINER:	Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if								